MV104

Silicon Tuning Diode

Dual Voltage Variable Capacitance Diode

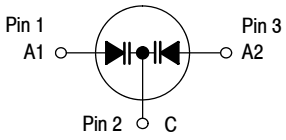
This device is designed for FM tuning, general frequency control and tuning, or any top-of-the-line application requiring back-to-back diode configurations for minimum signal distortion and detuning.

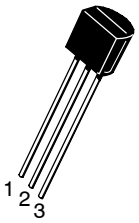
Features

- High Figure of Merit - Q = 140 (Typ) @ V_R = 3.0 Vdc, f = 100 MHz
- Guaranteed Capacitance Range - 37-42 pF @ V_R = 3.0 Vdc
- Dual Diodes - Save Space and Reduce Cost
- Monolithic Chip Provides Near Perfect Matching - Guaranteed ± 1.0% (Max) Over Specified Tuning Range
- This is a Pb-Free Device*

ON Semiconductor®

http://onsemi.com





STRAIGHT LEAD
BULK PACK

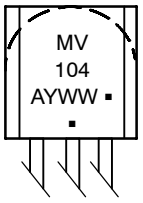
TO-92
CASE 29
STYLE 15

MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	32	Vdc
Forward Current	I_F	200	mAdc
Total Power Dissipation @ T_A = 25°C Derate above 25°C	P_D	280 2.8	mW mW/°C
Junction Temperature	T_J	+125	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MV104G	TO-92 (Pb-Free)	5000 Units / Bulk

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

	C_T, Diode Capacitance V_R = 3.0 Vdc, f = 1.0 MHz pF		Q, Figure of Merit V_R = 3.0 Vdc f = 100 MHz		C_R, Capacitance Ratio C_3/C_{30} f = 1.0 MHz	
Device	**Min**	**Max**	**Min**	**Typ**	**Min**	**Max**
MV104	37	42	100	140	2.5	2.8

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) **(EACH DIODE)**

Characteristic		Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage	(I_R = 10 μAdc)	$V_{(BR)R}$	32	-	-	Vdc
Reverse Voltage Leakage Current	T_A = 25°C (V_R = 30 Vdc) T_A = 60°C	I_R	- -	- -	50 500	nAdc
Diode Capacitance Temperature Coefficient	(V_R = 4.0 Vdc, f = 1.0 MHz)	TC_C	-	280	-	ppm/°C

TYPICAL CHARACTERISTICS (EACH DIODE)

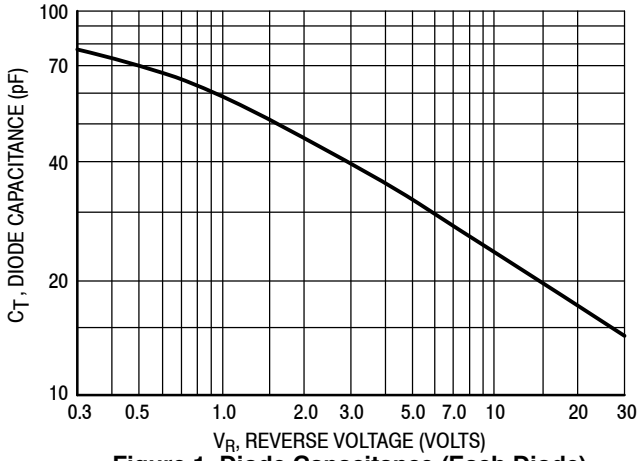


Figure 1. Diode Capacitance (Each Diode)

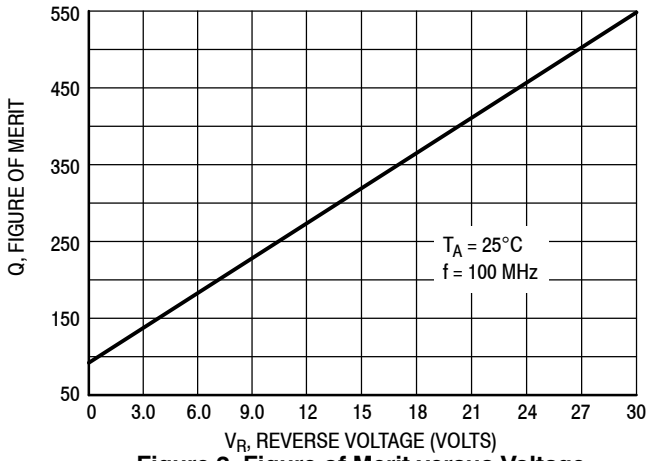


Figure 2. Figure of Merit versus Voltage

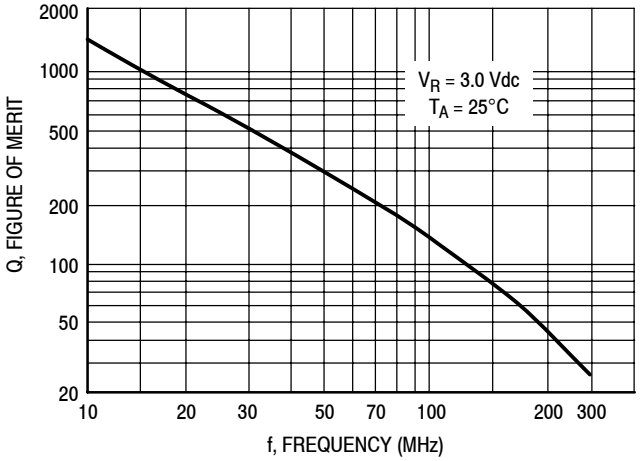


Figure 3. Figure of Merit versus Frequency

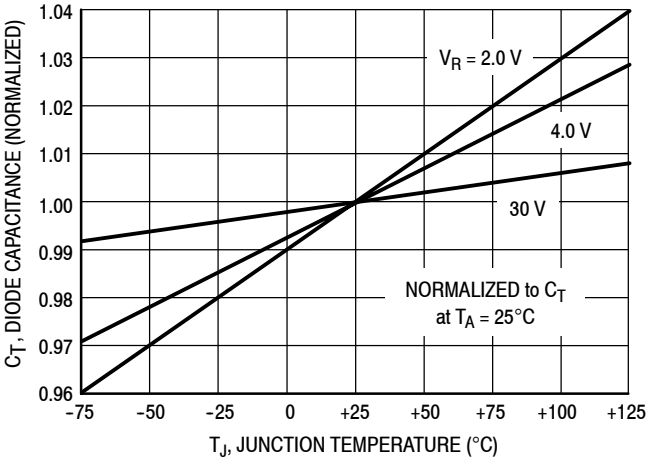


Figure 4. Diode Capacitance versus Temperature

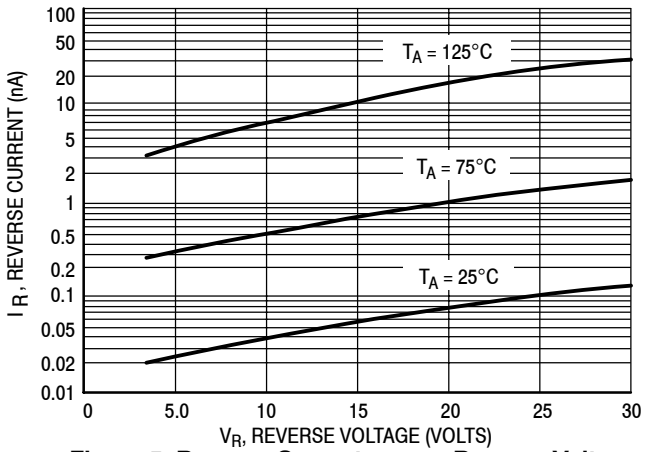
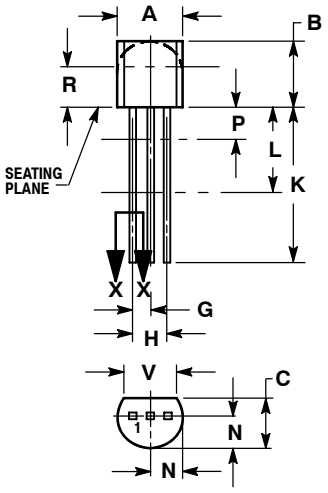


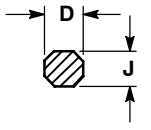
Figure 5. Reverse Current versus Reverse Voltage

PACKAGE DIMENSIONS

TO−92 (TO−226)
CASE 29−11
ISSUE AM



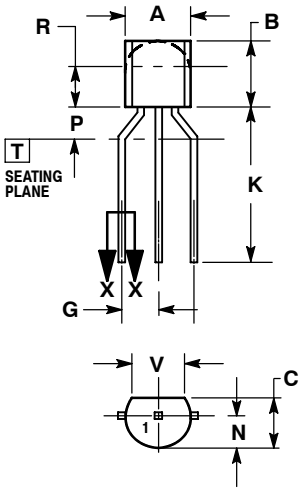
STRAIGHT LEAD
BULK PACK



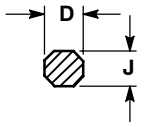
SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS	
DIM	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 15:
PIN 1. ANODE 1
2. CATHODE
3. ANODE 2

PUBLICATION ORDERING INFORMATION

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